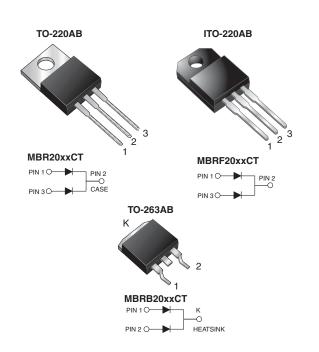
MBR(F,B)2035CT thru MBR(F,B)2060CT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	10 A x 2				
V_{RRM}	35 V to 60 V				
I _{FSM}	150 A				
V _F	0.57 V, 0.70 V				
T _J max.	150 °C				

FEATURES

- Guardring for overvoltage protection
- · Low power loss, high efficiency
- · Very low forward voltage drop
- High forward surge capability
- High frequency operation
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- · Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 gualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	MBR2035CT	MBR2045CT	MBR2050CT	MBR2060CT	UNIT
Maximum repetitive peak reverse voltage		V _{RRM}	35	45	50	60	
Working peak reverse voltage		V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage		V_{DC}	35	45	50	60	
Maximum average forward rectified current	total device		20				
at T _C = 135 °C	per diode	I _{F(AV)}	10				
Peak forward surge current 8.3 ms single half superimposed on rated load per diode	sine-wave	I _{FSM}		15	150		
Peak repetitive reverse surge current per dioc at $t_p = 2.0 \mu s$, 1 kHz	le	I _{RRM}	1	.0	0.5		
Voltage rate of change (rated V _R)		dV/dt	10 000				
Operating junction temperature range		T_{J}	- 65 to + 150				
Storage temperature range		T _{STG}	- 65 to + 175				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500			٧	



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBR2035CT	MBR2045CT	MBR2050CT	MBR2060CT	UNIT
Maximum instantaneous forward voltage per diode	V _F (1)	I _F = 10 A	T _C = 25 °C	0.65		0.80		V
		I _F = 10 A	T _C = 125 °C	0.57		0.70		
		I _F = 20 A	T _C = 25 °C	0.84		0.95		
		I _F = 20 A	T _C = 125 °C	0.	72	0.8	85]
Maximum reverse current at DC blocking voltage per diode	I _R ⁽²⁾	Rated V _R	T _C = 25 °C	0.1		0.15		mA
			T _C = 125 °C	1	5	15	50	IIIA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER SYMBOL MBR MBRF MBRB					UNIT	
Typical resistance from junction to case per diode	$R_{\theta JC}$	2.0	5.0	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2045CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2045CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2045CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2045CTHE3/45 1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2045CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

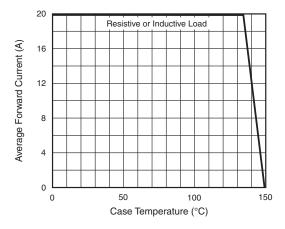


Fig. 1 - Forward Derating Curve (Total)

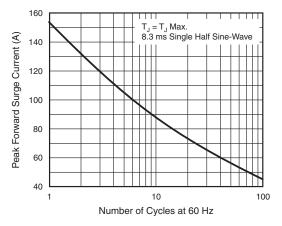


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

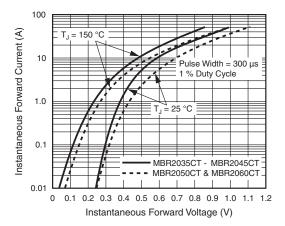


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

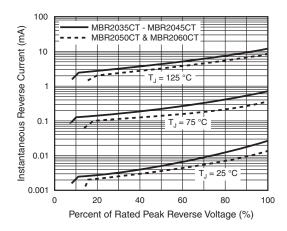


Fig. 4 - Typical Reverse Characteristics Per Diode

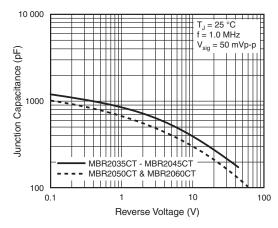


Fig. 5 - Typical Junction Capacitance Per Diode

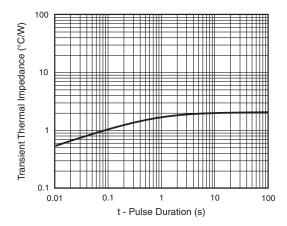


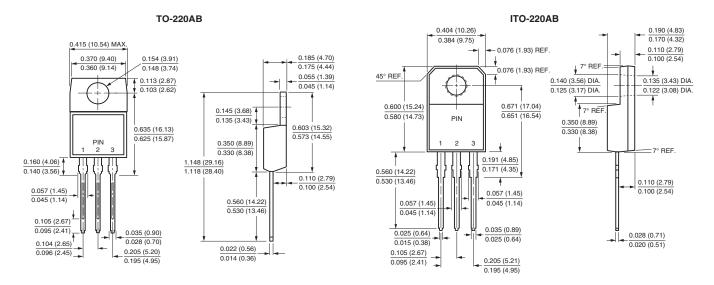
Fig. 6 - Typical Transient Thermal Impedance Per Diode



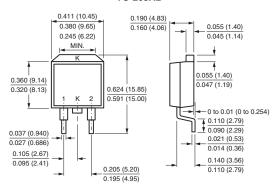
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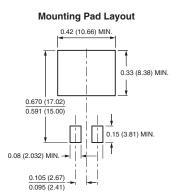
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB







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